xxxFN (JEDEC SOP) is not available in

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC164F,TC74VHC164FN,TC74VHC164FT,TC74VHC164FK

Note:

8-Bit Shift Register (S-IN, P-OUT)

The TC74VHC164 is an advanced high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of a serial-in, parallel-out 8-bit shift register with a CLOCK input and an overriding $\overline{\text{CLEAR}}$ input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $f_{max} = 175 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- · Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS164

Japan. TC74VHC164F SOP14-P-300-1.27A SOP14-P-300-1.27 TC74VHC164FN SOL14-P-150-1.27 TC74VHC164FT TSSOP14-P-0044-0.65A TC74VHC164FK

VSSOP14-P-0030-0.50

Weight

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

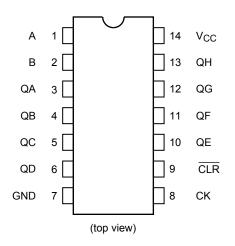
 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)

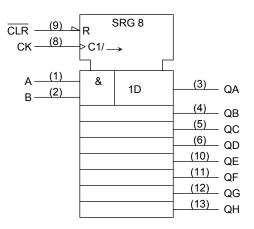
 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

Pin Assignment



IEC Logic Symbol



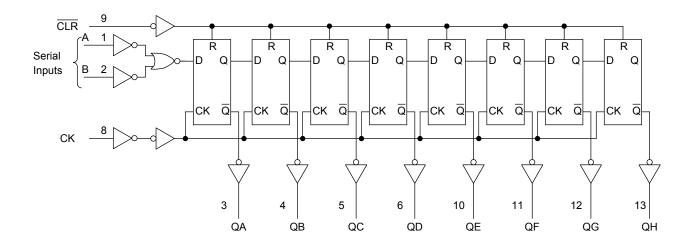
Truth Table

	Inp	uts		Outputs					
	СК	Seria	al IN	C	QB		QH		
CLR	CK	Α	В	QA	QВ		ğ		
L	Х	Х	Х	L	L		L		
Н	ightharpoons	X	X	No Change					
Н	Ļ	L	X	L	QAn		QG _n		
Н	Ļ	X	L	L	QAn		QG _n		
Н		Н	Н	Н	QA _n		QG _n		

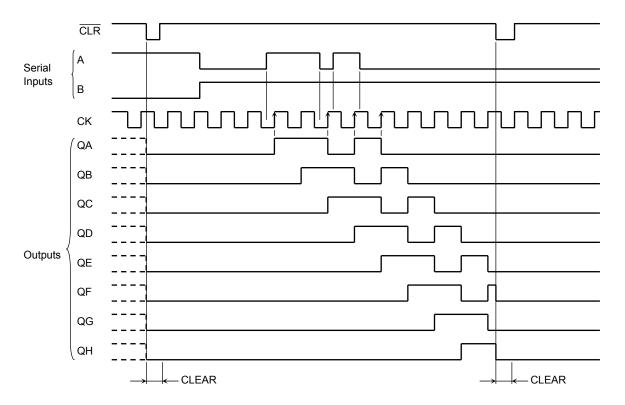
X: Don't care

QAn to QGn: The level of QA to QG, respectively, before the most recent positive edge of the clock.

System Diagram



Timing Chart



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	Vout	-0.5 to V _{CC} + 0.5	٧
Input diode current	lıK	-20	mA
Output diode current	lok	±20	mA
DC output current	I _{OUT}	±25	mA
DC V _{CC} /ground current	I _{CC}	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V _{OUT}	0 to V _{CC}	٧	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
input rise and rail time	ui/uv	0 to 20 (V _{CC} = 5 ± 0.5 V)	ris/V	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
Characteristics	Зуптыог	V		V _{CC} (V)	Min	Тур.	Max	Min	Max	Orme
High-level input voltage	V _{IH}	_			1.50 V _{CC} × 0.7	1 1	_ _	1.50 V _{CC} × 0.7	1 1	٧
Low-level input voltage	V_IL	_		2.0 3.0 to 5.5	_ _	_ _	0.50 V _{CC} × 0.3	_ _	0.50 V _{CC} × 0.3	V
High-level output voltage	Voн	V _{IN} = V _{IH} or V _{IL}	Ι _{ΟΗ} = -50 μΑ	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	_ _ _	1.9 2.9 4.4	_ _ _ v	
			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0 3.0 4.5	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1 0.36	_ _ _	0.1 0.1 0.1	٧
			I _{OL} = 4 mA	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _C	_C or GND	5.5	_	_	4.0	_	40.0	μΑ



Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	st Condition		Ta = 25°C		Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t _{w (L)}		3.3 ± 0.3	_	5.0	5.0	ne
(CK)	t _{w (H)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum pulse width	4		3.3 ± 0.3	_	5.0	5.0	20
(CLR)	t _{w (L)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum and undiman			3.3 ± 0.3	_	5.0	6.0	
Minimum set-up time	t _S	_	5.0 ± 0.5	_	4.5	4.5	ns
Minimo una la al di dina a			3.3 ± 0.3	_	0.0	0.0	
Minimum hold time	t _h	_	5.0 ± 0.5	_	1.0	1.0	ns
Minimum removal time	4		3.3 ± 0.3	_	2.5	2.5	
(CLR)	t _{rem}		5.0 ± 0.5	-	2.5	2.5	ns

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol		Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	.,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	8.4	12.8	1.0	15.0	- ns
Propagation delay time	t _{pLH}			50	_	10.9	16.3	1.0	18.5	
(CK-Q)	t _{pHL}	_	5.0 ± 0.5	15	_	5.8	9.0	1.0	10.5	
			3.0 ± 0.3	50	_	7.3	11.0	1.0	12.5	
	t _{рНL}	_	3.3 ± 0.3 · 5.0 ± 0.5 ·	15	_	8.3	12.8	1.0	15.0	- ns
Propagation delay time				50	_	10.8	16.3	1.0	18.5	
(CLR -Q)				15	_	5.2	8.6	1.0	10.0	
				50	_	6.7	10.6	1.0	12.0	
	f _{max} —		3.3 ± 0.3	15	80	125	_	65	_	
Maximum clock				50	50	75	_	45	_	MHz
frequency		_	5.0 ± 0.5	15	125	175	_	105	_	- IVITIZ
				50	85	115	_	75	_	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	_	76	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

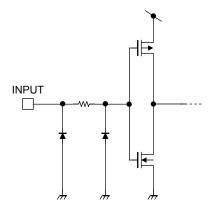
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

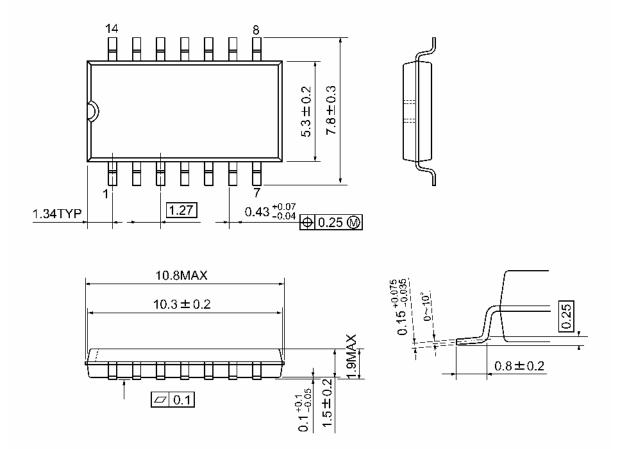
Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta =	- Unit	
Characteristics	Syllibol		V _{CC} (V)	Тур.	Max	Oill
Quiet output maximum dynamic V_{OL}	V_{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

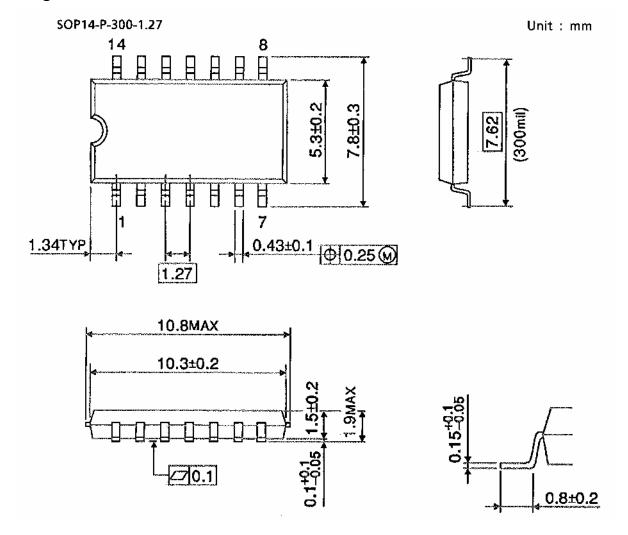
Input Equivalent Circuit



SOP14-P-300-1.27A Unit: mm



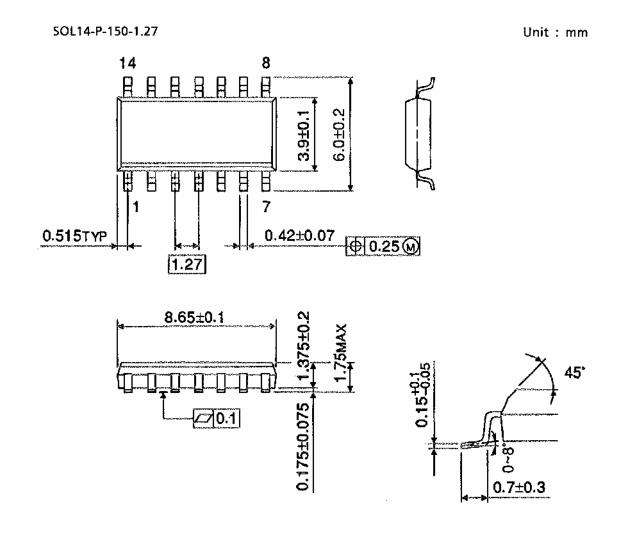
Weight: 0.18 g (typ.)



Weight: 0.18 g (typ.)



Package Dimensions (Note)

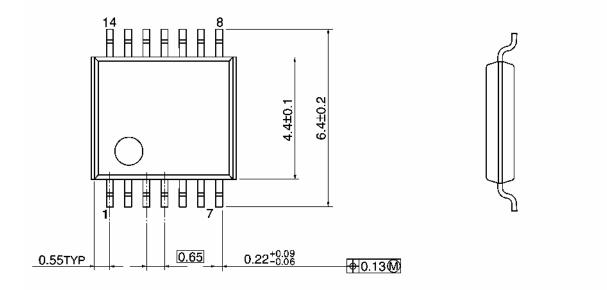


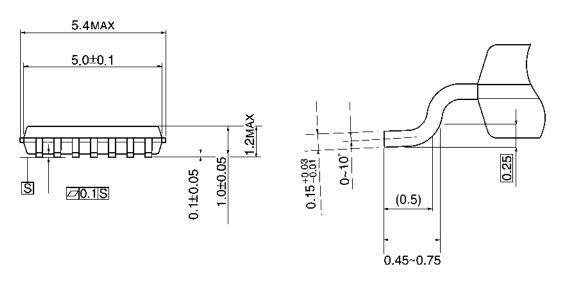
9

Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

TSSOP14-P-0044-0.65A Unit: mm

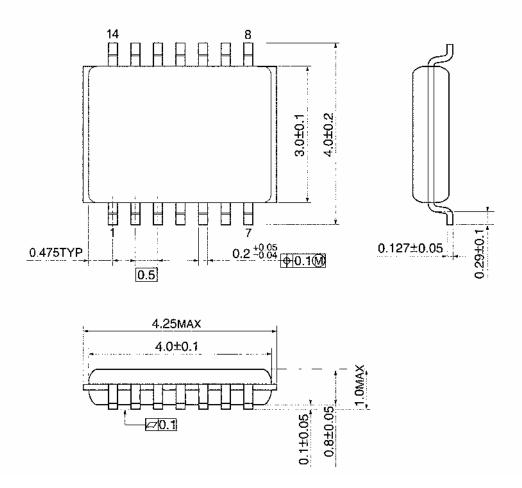




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Weight: 0.06 g (typ.)

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A VSSOP14-P-0030-0.50

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